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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Date Submitted: March 14, 2005

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Complete if Known	
Application Number	10/681,318
Filing Date	10/09/2003
First Named Inventor	Hisayo MOMOSE
Group Art Unit	2826
Examiner Name	Minh Loan Tran
Attorney Docket Number	016887-1094

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No.[1]	U.S. Patent Document Number	U.S. Patent Document Kind Code[2] (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No.[1]	Foreign Patent Document Office[3]	Number[4]	Kind Code[5] (if known)	Name of Patentee or Applicant of Cited Documents	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T[6]
MLT	D1	JP	05-315608		OMI TADAHIRO	11-26-1993	—	A
MLT	D2	JP	04-091478		TOSHIBA CORP.	03-24-1992	—	A

NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No.[1]	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.	T[6]
MLT	D3	M. SAITO et al., "An SPDD p-MOSFET Structure Suitable for 0.1 and Sub 0.1 Micron Channel Length and its Electrical Characteristics," 1992 International Electron Devices Meeting Technical Digest , pp. 897-900.	

Examiner Signature	Minhloan Tran	Date Considered	5/2005

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